

Now return to Jackson's harmonic oscillator model of the dielectric fun.

Recall this gives,

$$\boxed{\begin{aligned} N &= \# \text{ atoms / vol} \\ Z &= \# \text{ electrons / atom} \\ f_i &= \text{oscillator strengths} \end{aligned}}$$

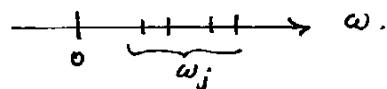
$$\epsilon = \epsilon_0 \left\{ 1 + \frac{Ne^2}{\epsilon_0 m} \sum_j \frac{f_j}{\omega_j^2 - \omega^2 - i\omega\gamma_j} \right\}, \quad \sum_j f_j = Z.$$

The model was crude but if resonant freq's ω_j and damping γ_j const's γ_j are understood in proper quantum mech'l sense the model is not bad for qualitative and (some) quantitative conclusions. First, a defn:

This was for a dielectric, the HO model involved only bound electrons. $\omega_p^2 = \frac{Ne^2 Z}{\epsilon_0 m} = (\text{plasma freq.})^2$.

Resonant ω_j 's are distributed along ω -axis and normally $\gamma_j \ll \omega_j$:

For an insulator (dielectric) the ω_j are nonzero.



Then note:

① ~~Re~~ Im ϵ small except when $|\omega - \omega_j| \approx \gamma_j$ for some j .

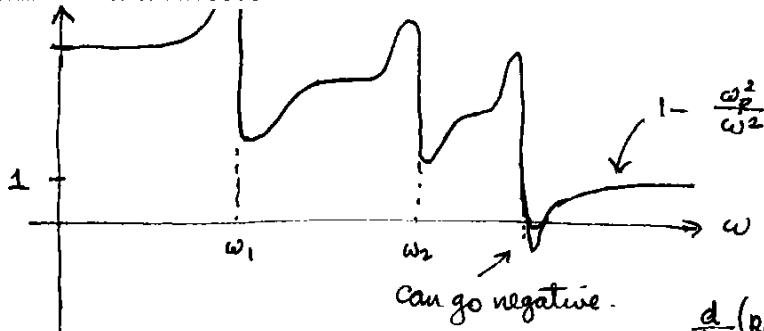
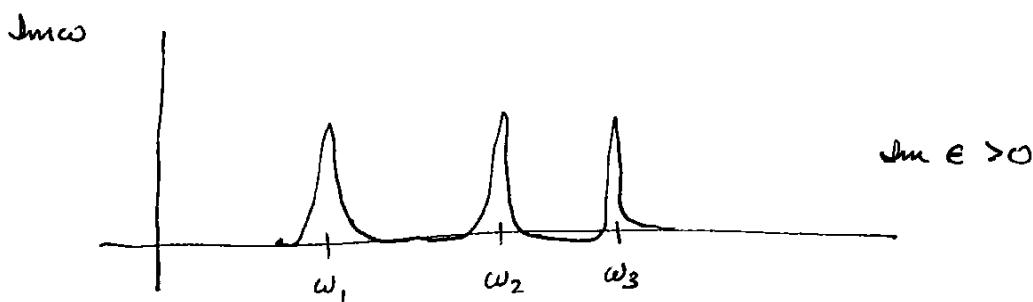
② ~~Re~~ As $\omega \rightarrow 0$, ϵ becomes real, and in fact

$$\epsilon(\omega=0) = \epsilon_0 \left\{ 1 + \frac{\omega_p^2}{Z} \sum_j \frac{f_j}{\omega_j^2} \right\} > \epsilon_0, \quad \frac{\epsilon}{\epsilon_0} > 1.$$

For example, in H_2O $\frac{\epsilon}{\epsilon_0} \approx 10$ @ $\omega=0$.

③ As $\omega \rightarrow \infty$, $\frac{\epsilon(\omega)}{\epsilon_0} \rightarrow 1 - \frac{\omega_p^2}{\omega^2} < 1$.
i.e., $\omega >$ any ω_j

④ So between $\omega=0$ and $\omega \rightarrow \infty$, \bullet Re $\epsilon(\omega)$ must decrease from > 1 to < 1 . But it doesn't do so monotonically.

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 $\frac{d}{d\omega}(\text{Re } \epsilon(\omega)) > 0$ most places
but < 0 in resonance zone.


something like this, resonance model.

this is for a dielectric. For a conductor, we have "free" charges and currents, produced by unbound electrons. We also have

$$\vec{J}_f(\vec{x}, \omega) = \sigma(\omega) \vec{E}(\vec{x}, \omega).$$

Conductor also has bound charges that can create polarization \vec{P} , usually don't worry about this at $\omega=0$, but for $\omega>0$ it's important too.

Look at ~~the~~ ω -domain Maxwell eqns for conductor, ~~with~~ ~~all~~ ~~fields~~ all fields are fun. of (\vec{x}, ω) , $\vec{D} = \epsilon(\omega) \vec{E}$, $\vec{B} = \mu(\omega) \vec{H}$, \vec{J}_f usual defn.

of ϵ ,

$$\epsilon(\omega) = \epsilon_0 (1 + \chi_e(\omega))$$

\uparrow describes polarization, $\vec{P} = \epsilon_0 \chi_e \vec{E}$.

$$\nabla \cdot (\epsilon \vec{E}) = \nabla \cdot \vec{D} = \rho_f$$

(Assume $\mu = \mu_0$).

$$\nabla \cdot \vec{B} = 0$$

$$\nabla \times \vec{E} = i\omega \vec{B} = i\omega \mu_0 \vec{H}$$

$$\nabla \times \vec{H} = \vec{J}_f + i\omega \vec{D} = \sigma \vec{E} - i\omega \epsilon \vec{E} = (\sigma - i\omega \epsilon) \vec{E}.$$

The ϵ incorporates effects of bound electrons, σ of conduction electrons.

Makes it logical to rewrite this,

$$\epsilon \rightarrow \epsilon_b = \epsilon \text{ due to bound electrons.}$$

$$\epsilon_{\text{tot}} = \epsilon_b + \frac{i\sigma}{\omega} \circ \cancel{\epsilon}.$$

Then $\nabla \times \vec{H} = -i\omega \epsilon_{\text{tot}} \vec{E}$.

As for Gauss, $\nabla \cdot \vec{D} = \nabla \cdot (\epsilon_b \vec{E}) = \rho_f$.

But continuity eqn for free charges is

$$\underbrace{\nabla \cdot \vec{J}_f}_{\text{or}} - i\omega \rho_f = 0$$

$$\nabla \cdot (\sigma \vec{E}), \text{ or } \rho_f = -\frac{i\sigma}{\omega} \nabla \cdot \vec{E}.$$

So, can write Gauss' law as $\nabla \cdot \left(\epsilon_b + \frac{i\sigma}{\omega} \right) \vec{E} = \nabla \cdot (\epsilon_{\text{tot}} \vec{E}) = 0$.

Thus, Maxwell eqns become

$$\left. \begin{array}{l} \nabla \cdot (\epsilon_{\text{tot}} \vec{E}) = 0 \\ \nabla \times \vec{H} = -i\omega \epsilon_{\text{tot}} \vec{E} \end{array} \right\} + \text{homog. eqns.}$$

$$\boxed{\epsilon_{\text{tot}} = \epsilon_b + \frac{i\sigma}{\omega}}$$

Same as in a dielectric with $\epsilon \rightarrow \epsilon_{\text{tot}}$.

Thus with this change we can treat dielectrics and conductors on an equal footing.

Can also incorporate conduction electrons into resonance model.

Recall, driven, damped HO model:

$$m \left(\ddot{\vec{x}} + \gamma_0 \dot{\vec{x}} + \omega_0^2 \vec{x} \right) = -e \vec{E}(\vec{x}, t).$$

If $\omega_0 = 0$, its a free particle with friction. γ_0 can be thought of as a collision time.

ϵ_0 leads to a term in the resonance model of the dielectric function with $\omega_0 = 0$, γ_0 = some damping.

$$\epsilon_{\text{tot}} = \epsilon_0 + \frac{Ne^2}{m} \frac{f_0}{-\omega^2 - i\omega\gamma_0} +$$



So conductivity comes from a resonance at $\omega = 0$

$$+ \frac{Ne^2}{m} \sum_{j \neq 0} \frac{f_j}{\omega_j^2 - \omega^2 - i\omega\gamma_j}$$

conduction elec's. ($j=0$ term)

bound elec's.

For insulators all $\omega_j > 0$,
but for conductors, one
 $\omega_b = 0$. ($j=0$).

Setting the conduction term to $\frac{i\sigma}{\omega}$, we get

$$\sigma = \frac{Ne^2}{m} \frac{f_0}{\gamma_0 - i\omega}$$

crude, qualitatively correct.

$f_0 = Z \times \text{frac. of electrons that are conduction electrons.}$

This model indicates that when $\omega \ll \gamma_0$, conductivity is real.

Now, dispersion relation from M.E.'s is

$$k^2 = \omega^2 \epsilon_{\text{tot}}(\omega) \mu_0.$$

also if $\omega \ll \omega_j$, then

$$\left| \frac{f_0}{-i\omega\gamma_0} \right| \ll \left| \frac{f_j}{\omega_j^2 - \omega^2 - i\omega\gamma_j} \right|$$

since $\mu = \mu_0$ here

\downarrow dominates at low ω

$$k^2 = \frac{\omega^2}{c^2} \frac{\epsilon_{\text{tot}}(\omega)}{\epsilon_0} = \frac{\omega^2}{c^2} \left(\frac{\epsilon_b(\omega)}{\epsilon_0} + \frac{i\sigma}{\epsilon_0 \omega} \right).$$

$$k^2 = \frac{i\sigma\omega}{c^2\epsilon_0} = i\sigma\mu_0\omega,$$

$$k = \left(\frac{1 \pm i}{\sqrt{2}} \right) \sqrt{\sigma\mu_0\omega}, \quad e^{ikz} \sim e^{-z/\delta},$$

$$\delta = \sqrt{\frac{2}{\sigma\mu_0\omega}} = \text{skin depth.}$$